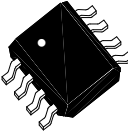


P-Channel Enhancement-Mode MOSFET (-30V, -12A)

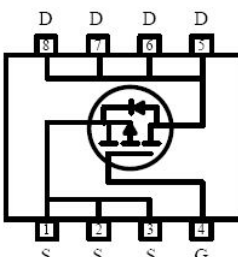
PRODUCT SUMMARY		
V_{DS}	I_D	$R_{DS(on)}$ (m-ohm) Max
-30V	-12A	13 @ $V_{GS} = -20V, I_D = -10A$
		20 @ $V_{GS} = -10V, I_D = -10A$
		28 @ $V_{GS} = -5V, I_D = -10A$

Features

- Advanced Trench Process Technology
- High Density Cell Design for Ultra Low On-Resistance
- Lead free product is acquired



SOP-8



Pin 1 / 2 / 3: Source
Pin 4: Gate
Pin 5 / 6 / 7 / 8: Drain

Order Information

Product	Package	Marking	Packing
A04407(PT)	SOP-8	PT4407	3000PCS/Reel

Absolute Maximum Ratings ($T_A=25^{\circ}C$, unless otherwise noted)

Symbol	Parameter	Ratings	Units
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current @ $T_A=25^{\circ}C$	-10	A
I_{DM}	Drain Current (Pulsed) ^a	-60	A
I_{AR}	Avalanche Current	30	A
E_{AR}	Repetitive Avalanche Energy $L=0.3mH$	135	mJ
P_D	Total Power Dissipation @ $T_A=25^{\circ}C$	3	W
	Total Power Dissipation @ $T_A=75^{\circ}C$	2.1	
I_S	Maximum Diode Forward Current	-2.1	A
T_j, T_{stg}	Operating Junction and Storage Temperature Range	-55 to +150	$^{\circ}C$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (PCB mounted) ^b	50	$^{\circ}C/W$

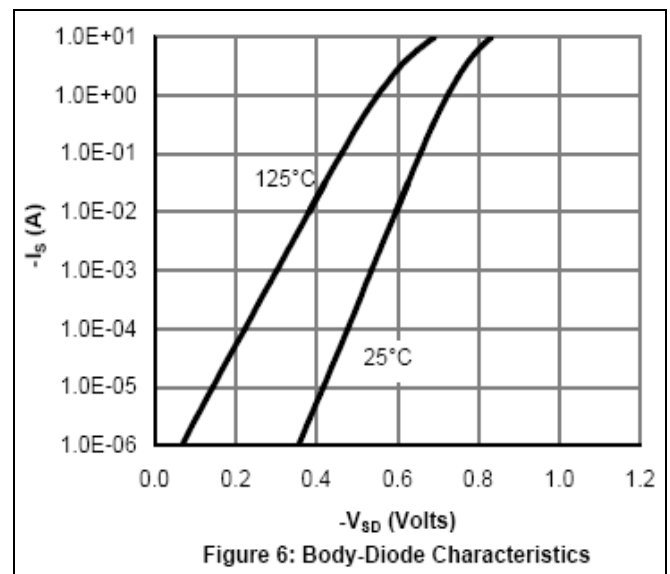
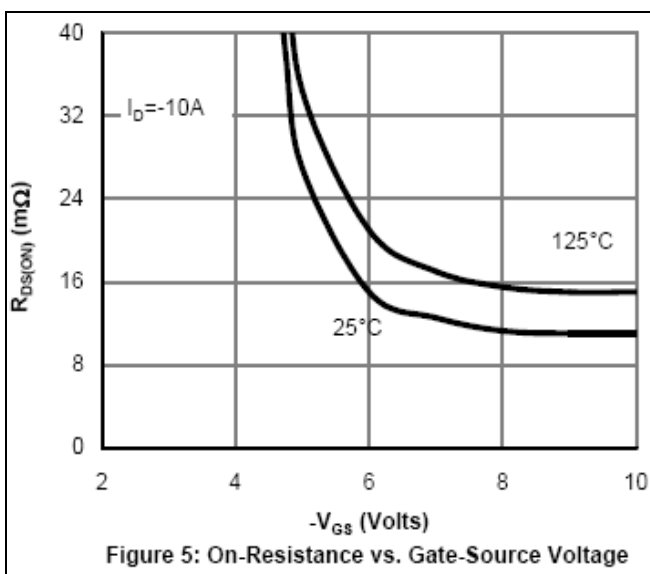
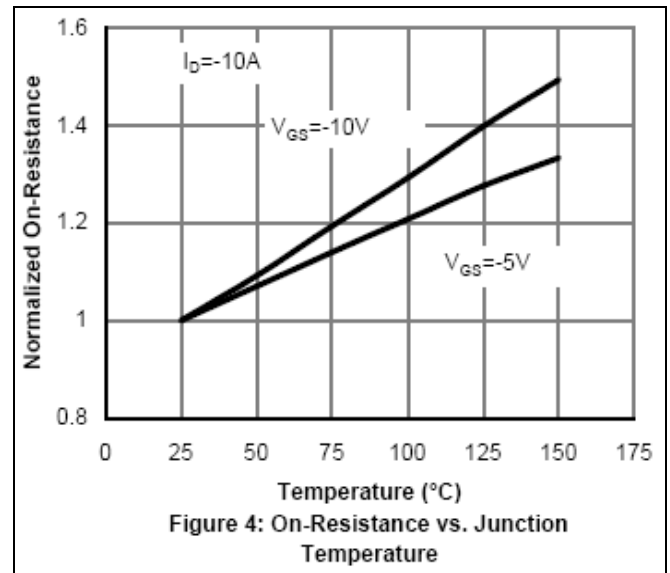
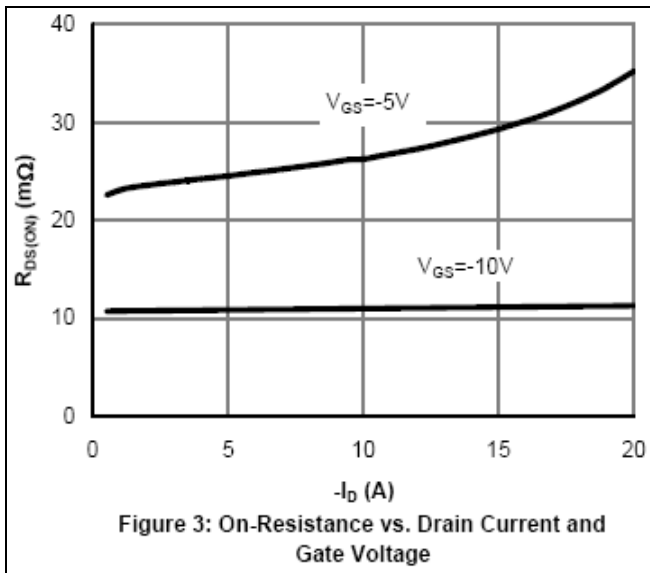
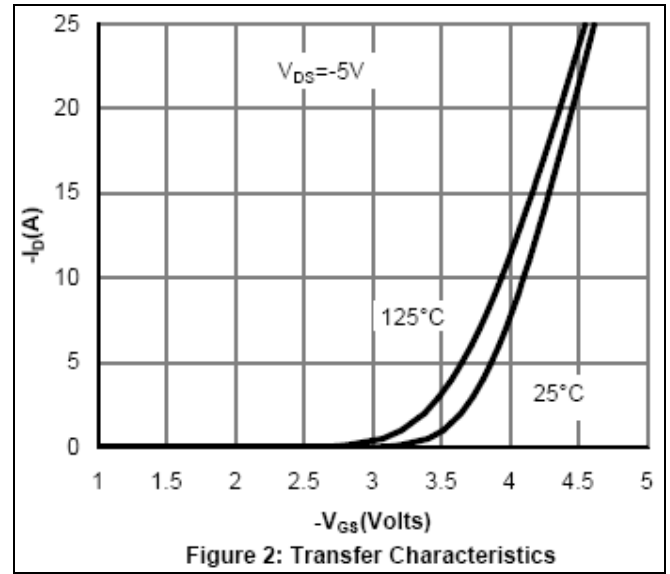
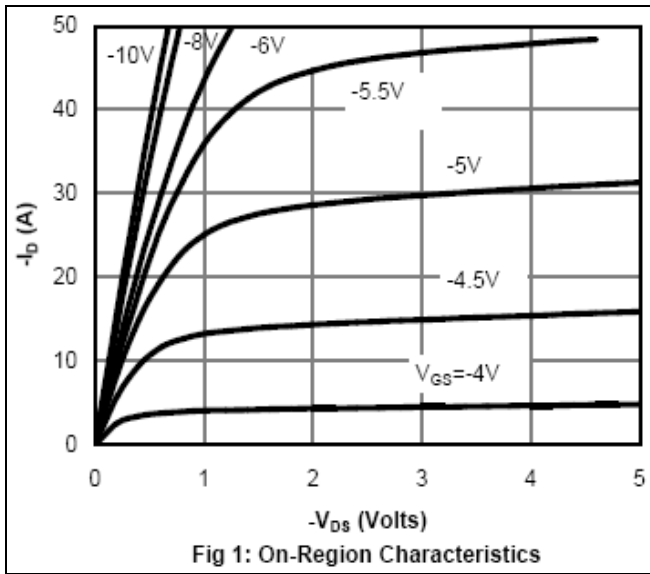
a: Repetitive Rating: Pulse width limited by the maximum junction temperature.
b: 1-in² 2oz Cu PCB board

Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise noted)

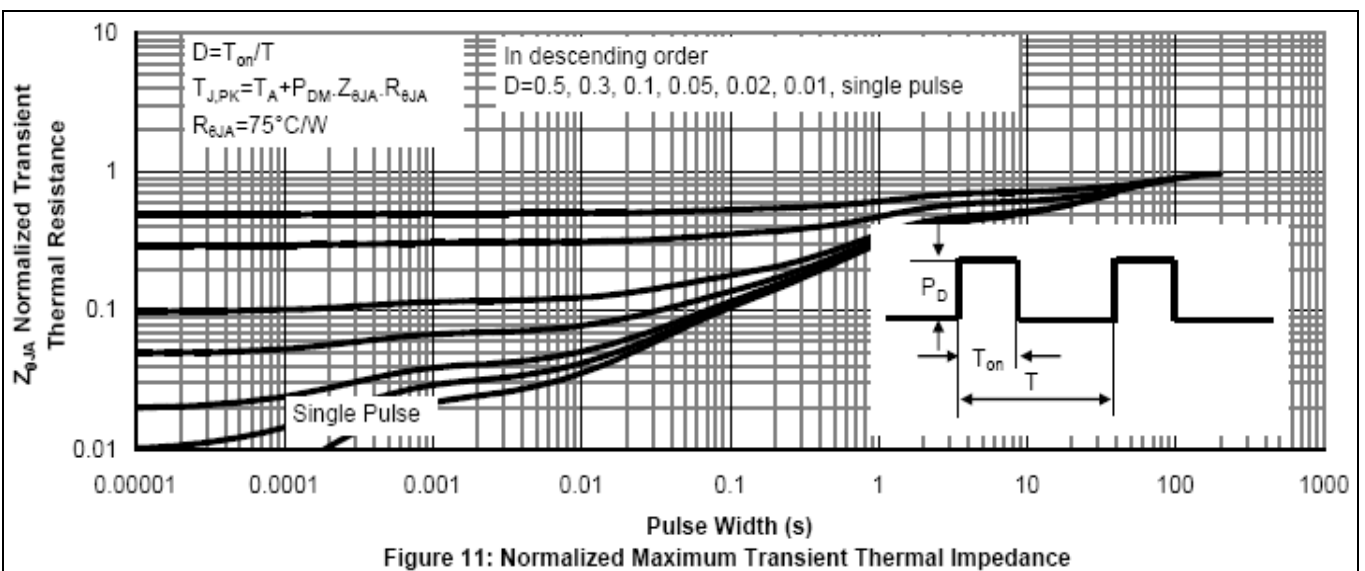
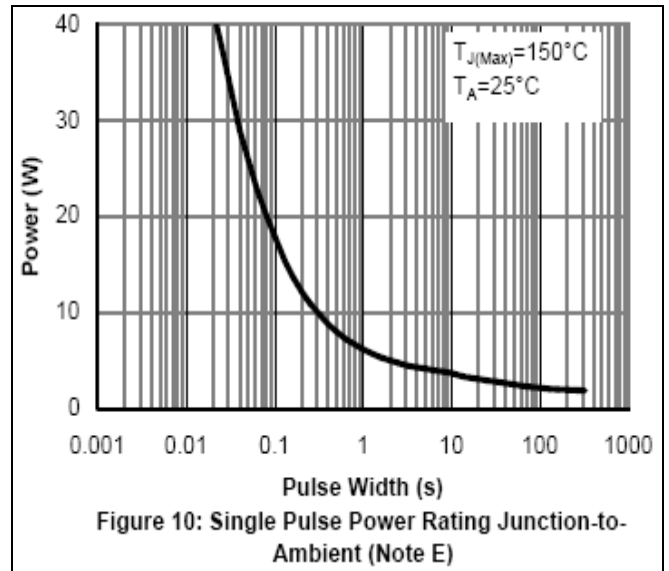
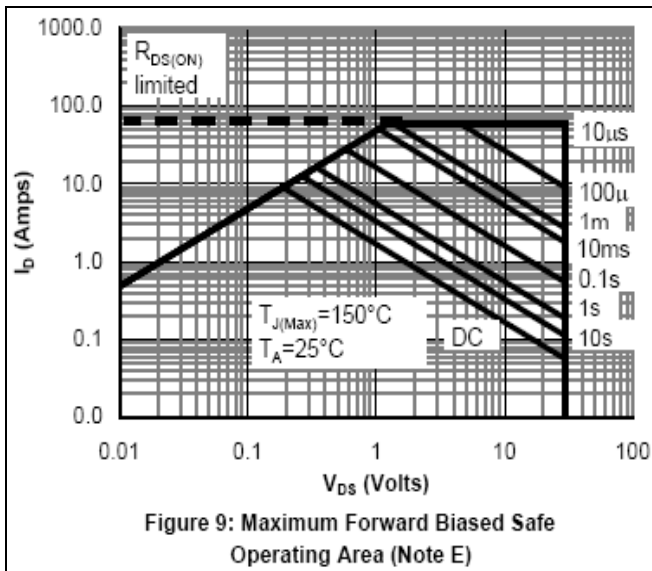
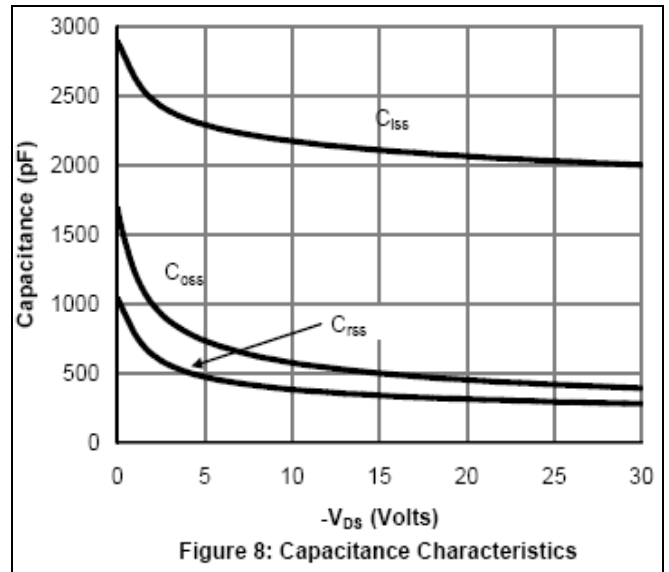
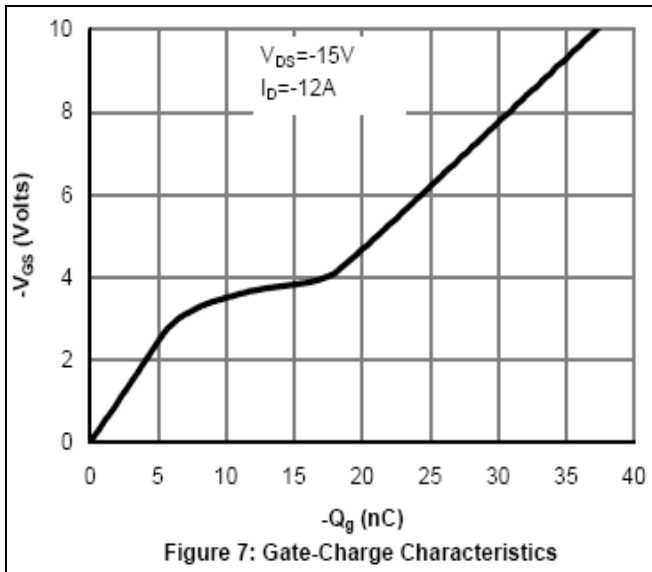
Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
• Off Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=-24V, V_{GS}=0V$	-	-	-1	uA
I_{GSS}	Gate-Body Leakage Current	$V_{GS}=\pm 25V, V_{DS}=0V$	-	-	± 100	nA
• On Characteristics^c						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0	-	-3.0	V
$I_{DS(on)}$	On State Drain Current	$V_{DS}=-5V, V_{GS}=-10V$	60	-	-	A
$R_{DS(on)}$	Drain-Source On-State Resistance	$V_{GS}=-10V, I_D=-10A$	-	-	14	m Ω
		$V_{GS}=-4.5V, I_D=-6A$	-	-	20	
g_{FS}	Forward Transconductance	$V_{DS}=-10V, I_D=-5A$	-	26	-	S
• Dynamic Characteristics^d						
C_{iss}	Input Capacitance	$V_{DS}=-15V, V_{GS}=0V, f=1\text{MHz}$	-	2076	2500	pF
C_{oss}	Output Capacitance		-	503	-	
C_{rss}	Reverse Transfer Capacitance		-	302	423	
R_g	Gate Resistance	$V_{DS}=0V, V_{GS}=0V, f=1\text{MHz}$	1	2	3	Ω
• Switching Characteristics^d						
Q_g	Total Gate Charge	$V_{DS}=-15V, I_D=-12A, V_{GS}=-10V$	-	37.2	-	nC
Q_{gs}	Gate-Source Charge		-	7	-	
Q_{gd}	Gate-Drain Charge		-	10.4	-	
$t_{d(on)}$	Turn-on Delay Time	$V_{DD}=-15V, R_L=1.25\Omega, V_{GS}=-10V, R_G=3\Omega$	-	12.4	-	nS
t_r	Turn-on Rise Time		-	8.2	-	
$t_{d(off)}$	Turn-off Delay Time		-	25.6	-	
t_f	Turn-off Fall Time		-	12	-	
t_{rr}	Reverse Recovery Time	$I_{DS}=-12A, dI/dt=100A/\mu S$	-	33	40	nS
Q_{rr}	Reverse Recovery Charge		-	23	-	nC
• Drain-Source Diode Characteristics						
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS}=0V, I_S=-1A$	-	-	-1	V
I_S	Drain-Source Diode Forward Current		-	-	-4.2	A

 Note: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$

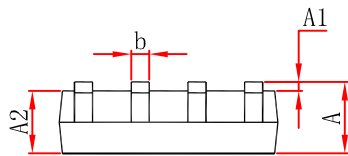
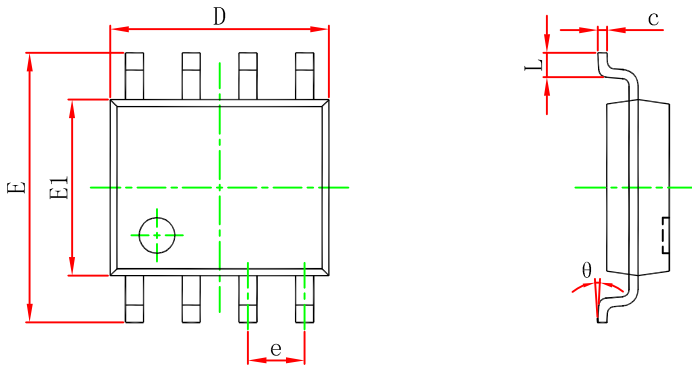
Characteristics Curve



Characteristics Curve

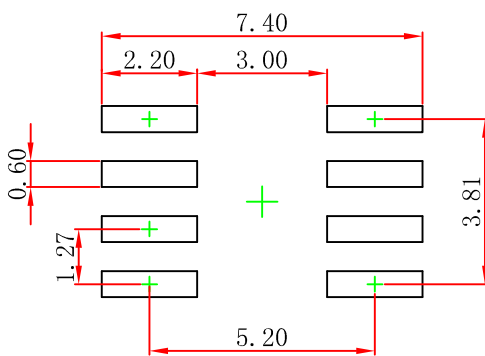


SOP8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

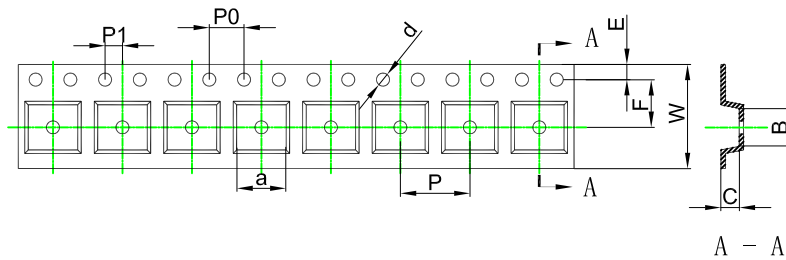
SOP8 Suggested Pad Layout



Note:

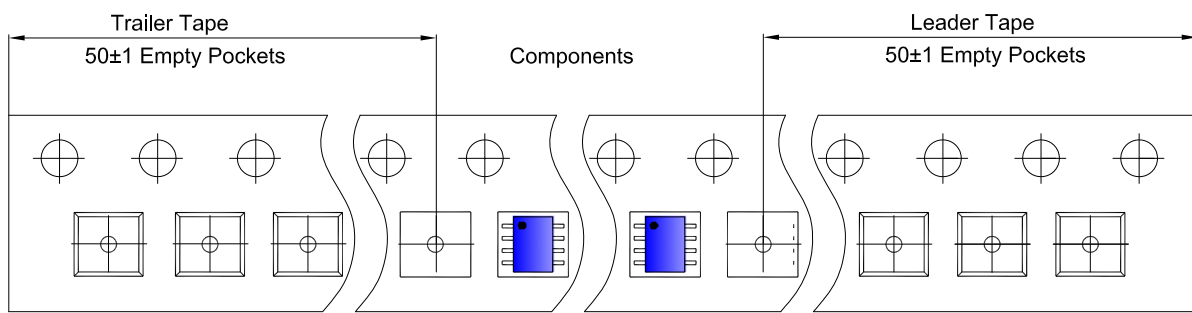
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

SOP8 Embossed Carrier Tape

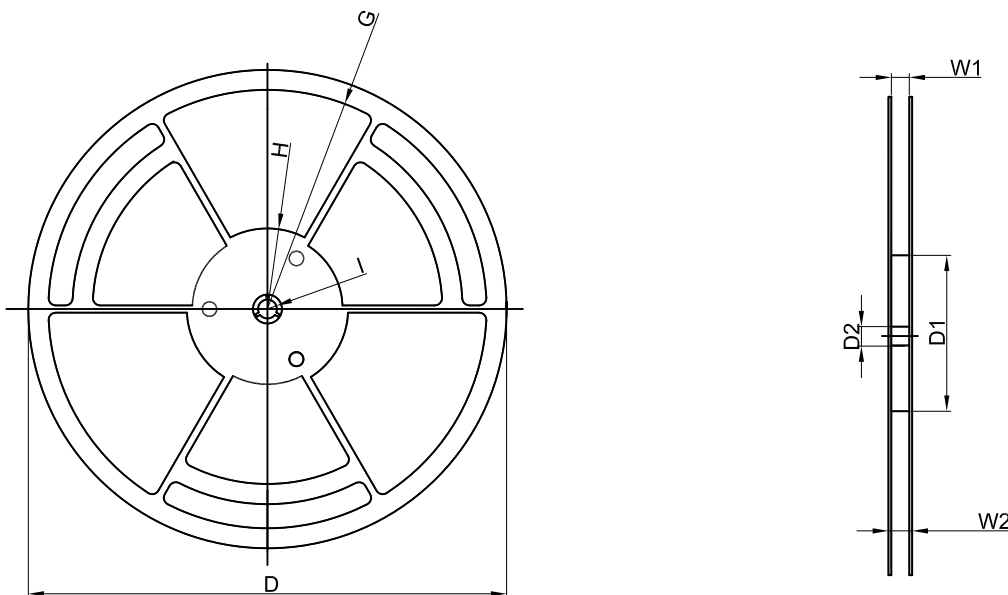


Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOP8	6.40	5.40	2.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

SOP8 Tape Leader and Trailer



SOP8 Reel



Dimensions are in millimeter									
Reel Option	D	D1	D2	G	H	I	W1	W2	
13" Dia	Ø330.00	100.00	13.00	R151.00	R56.00	R6.50	12.40	17.60	